Ordering number:EN2115B

NPN Epitaxial Planar Silicon Transistor

2SD1805

High-Current Switching Applications

Applications

· Strobes, voltage regulators, relay drivers, lamp drivers.

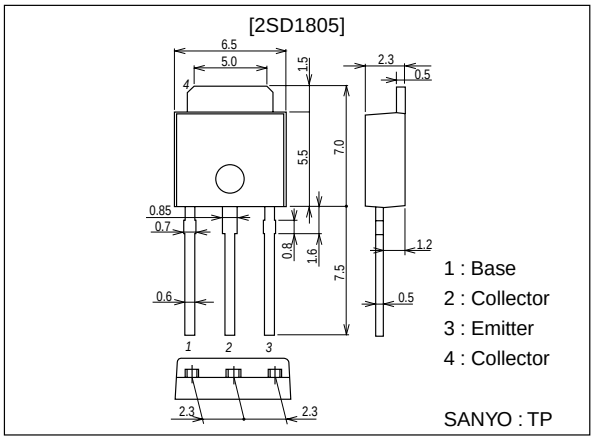
Features

· Low saturation voltage.
· Fast switching time.
· Large current capacity.
· Small and slim package making it easy to make 2SD1805-applied sets smaller.

Package Dimensions

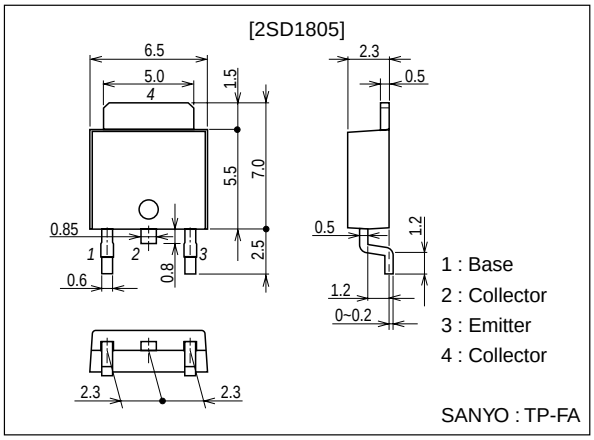
unit:mm

2045B



unit:mm

2044B



SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		60	V
Collector-to-Emitter Voltage	V_{CEO}		20	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		5	A
Collector Current (Pulse)	I_{CP}		8	A
Collector Dissipation	P_C		1	W
		Tc=25˚C	15	W
Junction Temperature	Tj		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

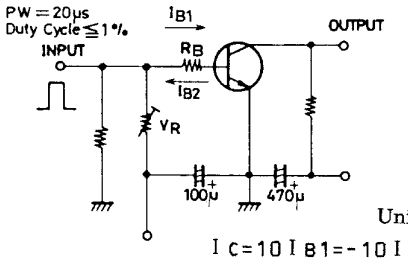
Electrical Characteristics at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=50V, I_E=0			100	nA
Emitter Cutoff Current	I_{EBO}	V_{EB}=5V, I_C=0			100	nA
DC Current Gain	$h_{FE}1$	V_{CE}=2V, I_C=500mA	120*		560*	
	$h_{FE}2$	V_{CE}=2V, I_C=3A	95			
Gain-Bandwidth Product	f_T	V_{CE}=10V, I_C=50mA		120		MHz
Output Capacitance	C_{ob}	V_{CB}=10V, f=1MHz		45		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=3A, I_B=60mA		220	500	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C=3A, I_B=60mA			1.5	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=10μA, I_E=0	60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA, R_{BE}=∞	20			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}	See specified Test Circuit.		300		ns
Fall Time	t_f	See specified Test Circuit.		40		ns

* : The 2SD1805 is classified by 500mA h_{FE} as follows :

120	E	200	160	F	320	280	G	560

Switching Time Test Circuit



Unit (capacitance : F)

I_C=10 I_{B1}=–10 I_{B2}=2A, V_{CC}=10V